－HALF DUPLEX ASYNCHRONOUS 2400bps FSK MODEM
－Tx CARRIER FREQUENCY SYNTHESIZED FROM EXTERNAL CRYSTAL
－LOW DISTORTION Tx SIGNAL
－Rx SENSITIVITY BETTER THAN 1 mV RMs
－CARRIER DETECTION
－WATCH－DOG INPUT
－RESET AND MASTER CLOCK OUTPUTS FOR MICROCONTROLLER
－POWER AMPLIFIER BIAS CURRENT CON－ TROL（HIGH IMPEDANCE IN Rx MODE）
－SIMPLE AND ECONOMICAL APPLICATION SCHEMATICS
－COMPATIBLE WITH CENELEC EN 50065－1 AND FCC SPECIFICATION
－CARRIER DETECT CLAMPING ON RxD PROGRAMMABLE（ALLOWING DEMODULA－ TION ON VERY LOW RECEIVE LEVEL， 1 mV Rms TYPICALLY）

## DESCRIPTION

The ST7537HS1 is a half duplex asynchronous FSK MODEM designed for home automation com－ munication on the domestic electric mains which complies with the EN 50065－1 CENELEC stand－ ard．
It mainly operates from a 10 V power supply and a 5 V power supply for the microcontroller digital in－ terface．

It is interfaced to the power line by an external driver，and a transformer（see Application Sche－ matic Diagram）．Its data transmission rate is 2400 bps and its carrier frequency is 132.45 kHz ．


PIN CONNECTIONS


## ST7537HS1

## PIN DESCRIPTION

| Pin <br> Name | Pin <br> Number | Pin <br> Type | Description |
| :---: | :---: | :---: | :--- |
| V $_{\text {CM }}$ | 1 | Analog | Common Mode Voltage |
| AV | 2 | Supply | Analog Power Supply ：10V $\pm 5 \%$ |
| RAI | 3 | Analog | Receive Analog Input |
| RxFO | 4 | Analog | Receive Filter Output |
| TxIFI | 5 | Analog | Transmit and Intermediate Frequency Filters Test Input（mode TEST3） |
| PAFB | 6 | Analog | Power Amplifier Feed－back Input |
| ATO | 7 | Analog | Analog Transmit Output |
| PABC | 8 | Digital（10V） | Power Amplifier Bias Current Control Complementary Output |
| PABC | 9 | Digital（10V） | Power Amplifier Bias Current Control Output |
| TEST1 | 10 | Digital | Tx to Rx Automatic Mode Switching Control Input |
| TEST2 | 11 | Digital | Automatic Mode Switching Time and Watch－dog Time Reduction Control Input |
| TEST3 | 12 | Digital | TxIFI Selection Input |
| TEST4 | 13 | Digital | Undelayed Reset Input |
| DV | 14 | Supply | Digital Power Supply ：10V $\pm 5 \%$ |
| DVSS | 15 | Supply | Digital Ground ：OV |
| XTAL1 | 16 | Digital（10V） | Crystal Oscillator Input |
| XTAL2 | 17 | Digital（10V） | Crystal Oscillator Output |
| MCLK | 18 | Digital | Master Clock Output |
| $\overline{\text { WD }}$ | 19 | Digital | Watch－dog Input |
| Rx／Tx | 20 | Digital | Rx or Tx Mode Selection Input |
| $\overline{\text { CD }}$ | 21 | Digital | Carrier Detect Output |
| TxD | 22 | Digital | Transmit Data Input |
| RxD | 23 | Digital | Receive Data Output |
| RSTO | 24 | Digital | Reset Output |
| DVCC | 25 | Supply | Digital Buffers Supply Voltage $: 5 \mathrm{~V} \pm 5 \%$ |
| IFO | 26 | Analog | Intermediate Frequency Filter Output |
| DEMI | 27 | Analog | Demodulator Input |
| AV | 28 | Supply | Analog Ground ：OV |
|  | 28 |  |  |

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## BLOCK DIAGRAM



## TRANSMIT SECTION

The transmit mode is set when $R x / \overline{T x}=0$ ，if $R x / \overline{T x}$ is held at 0 longer than 1 second，then the device switches automatically in the Rx mode．A new activation of the Tx mode requires $\mathrm{Rx} / \mathrm{Tx}^{\text {x }}$ to be returned to 1 for a minimum 2 microsecond period before being set to 0 ．
The Transmit Data（TxD）enter asynchronously the FSK modulator with a nominal intra－message data rate of 2400 bps ．
The basic transmit frequencies are ：
$-\mathrm{f}(\mathrm{TxD}=0)=133.05 \mathrm{kHz}$
$-\mathrm{f}(\mathrm{TxD}=1)=131.85 \mathrm{kHz}$
These frequencies are synthesized from a 11.0592 MHz crystal oscillator；their precision is the same as the crystal one＇s（100ppm）．
The modulated signal coming out of the FSK modu－ lator is filtered by a switched－capacitor band－pass filter（Tx band－pass）in order to limit the output spectrum and to reduce the level of harmonic com－ ponents．
The final stage of the Tx path consists of an opera－ tional amplifier which needs a feed－back signal （PAFB）from the power amplifier as shown on Application Schematic Diagram．
In Tx mode the Receive Data（ RxD ）signal is set to 1 ．

## RECEIVE SECTION

The receive section is active when $R x / \overline{T x}=1$ ．
The Rx signal is applied on RAI and filtered by a band－pass switched capacitor filter（Rx band－pass） centered on the carrier frequency and whose band－ width is around 12 kHz ．
The Rx filter output is amplified by a 20 dB gain stage which provides symetrical limitations for large voltage．The resulting signal is down－con－ verted by a mixer which receives a local oscillator synthesized by the FSK modulator block．Finally an intermediate frequency band－pass filter（IF band－ pass）whose central frequency is 5.4 kHz improves the signal to noise ratio before entering the FSK demodulator．
The coupling of the intermediate frequency filter output（IFO）to the FSK demodulator input（DEMI） is made by an external capacitor $\mathrm{C} 5(100 \mathrm{nF} \pm 10 \%$ ， 10 V ）which cancels the Rx path offset voltage．
The RxD output delivers the demodulated signal if the carrier detect（ $\overline{C D}$ ）signal is low and is set to high level when $C D=1$ ．
The RxD output can delivers the demodulated signal whatever the level of $\overline{C D}(0$ or 1 ）if $\mathrm{Rx} / \overline{\mathrm{Tx}}=1$ and TxD $=0$（see Figure 1）．

Figure 1 ：Data Timing Chart


## ADDITIONAL DIGITAL AND ANALOG FUNC－ TIONS <br> Time base

A time base section delivers all the internal clocks from a crystal oscillator（ 11.0592 MHz ）．The crystal is connected between XTAL1 and XTAL2 pins and needs two external capacitors C3 and C4（22pF $\pm 10 \%, 10 \mathrm{~V}$ ）for proper operation．

## Reset and watch－dog

The reset output（RSTO）is driven high when the supply voltage is lower than Vrh（typically 7.6 V ）with an hysteresis Vrh－Vrl（typically 300 mV ）or when no negative transition occurs on the watch－dog input （WD）for more than 1.5 second（see the timing chart on Figure 2）．When a reset occurs RSTO is held high for at least 50ms．

## Signal detection

The Carrier Detect output（ $\overline{C D}$ ）is driven low when the input signal amplitude on RAI is greater than $V_{C D}$ for at least TCD（typically 6 ms see the timing chart on Figure 3）．When the input signal desap－ pears or becomes lower than $\mathrm{V}_{\mathrm{CD}}$ ， CD is held low for at least Tcd before returning to a high level．$V_{C D}$ is the carrier detection threshold voltage which is set internally to detect 5 mV RMs typically．

## External power amplifier bias control

Two dedicated digital output（PABC and $\overline{\mathrm{PABC}}$ ） delivering a signal between 0 V and 10 V are driven
low respectively high，when the circuit is set in the receive mode（ $\mathrm{Rx} / \mathrm{Tx}=1$ ）or when the transmit mode time out（ 1 second）is exceeded；in the same time the output ATO is put in a high impedance state．

## TESTING FEATURES

－An additionnal amplifier allows the observation of the Rx band－pass filter output on pin RxFO．
－A direct input to the Tx band－pass filter and to the IF filter（TxIFI）is selected when TEST3＝ 1 ．
－The 1 second normal duration of the $T x$ to Rx mode automatic switching is reduced to $488 \mu \mathrm{~s}$ and the 1.5 second watch－dog time out is reduced to $46.3 \mu \mathrm{~s}$ when TEST2＝ 1 ．
－When TEST1＝ 1 the Tx to Rx mode automatic switching is desactivated and the functional mode of the circuit is fully controlled by $\mathrm{Rx} / \mathrm{Tx}$ ．
－TEST4 is a reset input which allows an undelayed control of RSTO and of the internal state of the circuit．

## POWER SUPPLIES WIRING PRECAUTIONS

The ST7537HS1 has two positive power supply terminals（AV （AVss，DVss）in order to separate internal analog and digital supplies．The analog and digital termi－ nals of each supply pair must be connected to－ gether externally for proper operation．
The VDD must be protected against short－circuit for proper operation．

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ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
| :---: | :---: | :---: | :---: |
| $\mathrm{AV}_{\mathrm{DD}} / \mathrm{DV}_{\text {DD }}$ | Supply Voltage（1） | －0．3，＋ 12 | V |
| $\mathrm{V}_{1}$ | Digital Input Voltage | $D V_{S S}-0.3, D V_{D D}+0.3$ | V |
| Vo | Digital Output Voltage（microcontroller interface） | DV ${ }_{\text {Ss }}-0.3, \mathrm{DV}$ Cc +0.3 | V |
| Vo | Digital Output Voltage（PABC and $\overline{\text { PABC }}$ ） | DV $\mathrm{SS}^{-0.3, ~ D V} \mathrm{DD}+0.3$ | V |
| lo | Digital Output Current | $-5,+5$ | mA |
| VI | Analog Input Voltage | $A V_{S S}-0.3, A V_{\text {DD }}+0.3$ | V |
| Vo | Analog Output Voltage | $\mathrm{AV}_{S S}-0.3, \mathrm{AV}$ DD +0.3 | V |
| lo | Analog Output Current | $-5,+5$ | mA |
| PD | Power Dissipation | （1） 500 | mW |
| Toper | Operating Temperature | $0,+70$ | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ | Storage Temperature | $-55,+150$ | ${ }^{\circ} \mathrm{C}$ |

Notes：1．The voltages are referenced to $A V$ ss and $D V$ ss．
2．Absolute maximum ratings are values beyond which damage to device may occur．Functional operation under these conditions is not implied．

## GENERAL ELECTRICAL CHARACTERISTICS

（A／DV ${ }_{D D}=10 \mathrm{~V}, \mathrm{~A} / D V_{S S}=0 \mathrm{~V}, \mathrm{DV} \mathrm{CC}=5 \mathrm{~V}$ and $0^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{amb}} \leq 70^{\circ} \mathrm{C}$ ，unless otherwise specificied）

| Symbol | Parameter | Test Conditions | Min． | Typ． | Max． | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $A V_{D D}$ DV ${ }_{D D}$ | Supply Voltage |  | 9.5 | 10 | 10.5 | V |
| AldD + DIDD | Supply Current |  |  | 30 | ， | mA |
| DVCC | Digital Output Supply Voltage |  | 4.75 |  | 5.25 | V |
| DIcc | Digital Output Supply Current |  |  | 1.5 |  | mA |
| $\mathrm{V}_{\mathrm{IH}}$ | High Level Input Voltage | Digital Inputs | 4.2 |  |  | V |
| VIL | Low Level Input Voltage | Digital Inputs |  |  | 0.8 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | High Level Output Voltage | $\mathrm{I}_{\mathrm{OH}}=-100 \mu \mathrm{~A}$ <br> －Digital Outputs <br> －Digital Outputs PABC and $\overline{\text { PABC }}$ | $\begin{aligned} & 4.9 \\ & 9.8 \end{aligned}$ |  |  | V |
| Vob | Low Level Output Voltage | $\mathrm{loL}=100 \mu \mathrm{~A}$ <br> －Digital Outputs <br> －Digital Outputs PABC and $\overline{\text { PABC }}$ |  |  | $\begin{aligned} & 0.1 \\ & 0.2 \end{aligned}$ | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| DC | Duty Cycle | MCLK Output， $\mathrm{C}_{L}=15 \mathrm{pF}$ | 40 |  | 60 | \％ |

## TRANSMITTER ELECTRICAL CHARACTERISTICS

（A／DV $D D=10 \mathrm{~V}, \mathrm{~A} / D V_{S S}=0 \mathrm{~V}, D V_{C C}=5 \mathrm{~V}$ and $0^{\circ} \mathrm{C} \leq \mathrm{T}_{\text {amb }} \leq 70^{\circ} \mathrm{C}$ ，unless otherwise specificied）

| Symbol | Parameter | Test Conditions | Min． | Typ． | Max． | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| VTAC | Max Carrier Output AC Voltage | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=5.6 \mathrm{k} \Omega \\ & \mathrm{R}_{\mathrm{L}}\left(\mathrm{~A} \mathrm{~A}_{\mathrm{SS}}\right)=5.6 \mathrm{k} \Omega \\ & \mathrm{R}(\mathrm{ATO}, \mathrm{PAFB})=1 \mathrm{k} \Omega \end{aligned}$ | 0.8 | 1.0 | 1.3 | VRMS |
| HD2 | Second Harmonic Distortion |  |  | －50 |  | dB |
| HD3 | Third Harmonic Distortion |  |  | －60 |  | dB |
| FD | FSK Peak－to－peak Deviation |  |  | 1200 |  | Hz |

## ST7537HS1

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## RECEIVER ELECTRICAL CHARACTERISTICS

（A／DVDD $=10 \mathrm{~V}, \mathrm{~A} / D V_{S S}=0 \mathrm{~V}, \mathrm{DV} C \mathrm{C}=5 \mathrm{~V}$ and $0^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{amb}} \leq 70^{\circ} \mathrm{C}$ ，unless otherwise specificied）

| Symbol | Parameter | Test Conditions | Min． | Typ． | Max． | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| VIN | Input Sensitivity |  |  | 1 | 10 | mV RMS |
| $\mathrm{V}_{\text {IN }}$ | Maximum Input Signal |  |  |  | 2 | $\mathrm{V}_{\text {RMS }}$ |
| Rin | Input Impedance |  | 15 |  |  | $\mathrm{k} \Omega$ |
| GRx | Receive Gain | $\mathrm{f}=132.45 \mathrm{kHz}$ |  | 20 |  | dB |
| BER | Bit Error Rate（1） | $\mathrm{S} / \mathrm{N}=15 \mathrm{~dB}, \mathrm{~S}=10 \mathrm{mV} \mathrm{RmS}^{\text {，}} \mathrm{N}:$ white |  | $10^{-5}$ | $10^{-3}$ |  |
| tdem | Demodulation Time | Alternate 0， 1 sequence |  | 3 |  | T bit |
| $\mathrm{V}_{C D}$ | Carrier Detection Level | $\mathrm{f}=132.45 \mathrm{kHz}$ ，sine wave |  | 5 | 10 | mV RMS |

Note 1 ：This parameter is guaranteed by correlation

ADDITIONAL DIGITAL AND ANALOG FUNCTIONS ELECTRICAL CHARACTERISTICS
$\left(\mathrm{A} / \mathrm{DV}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{~A} / \mathrm{DV} \mathrm{SS}=0 \mathrm{~V}, \mathrm{DV} \mathrm{CC}=5 \mathrm{~V}\right.$ and $0^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{amb}} \leq 70^{\circ} \mathrm{C}$ ，unless otherwise specificied）

| Symbol | Parameter | Test Conditions | Min． | Typ． | Max． | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {RH }}$ | High Level Reset Voltage | See Figure 2 |  | 7.9 |  | V |
| $V_{\text {RL }}$ | Low Level Reset Voltage | See Figure 2 |  | 7.6 |  | V |
| trst | Reset Time | See Figure 2 | 50 |  |  | ms |
| twd | Watch－dog Pulse Width | See Figure 2 | 500 |  |  | ns |
| twm | Watch－dog Pulse Period | See Figure 2 | 800 |  |  | $\mu \mathrm{S}$ |
| tout | Watch－dog Time Out | See Figure 2 |  |  | 1.5 | s |
| $\mathrm{t}_{\mathrm{CD}}$ | Carrier Detection Time | See Figure 3 | 3 |  | 6.5 | ms |

Figure 2 ：Reset and Watch－dog Timing Chart


Figure 3 ：Carrier Detection Timing Chart


## FILTER TEMPLATES

## Receive and Transmit Filter

| Frequency <br> （kHz） | Gain（dB） |  |  |
| :---: | :---: | :---: | :---: |
|  | Min． | Typ． | Max． |
| 92 |  |  | -30 |
| 126.45 | -5 | -3 | -2 |
| Ref 132.45 |  | 0 |  |
| 138.45 | -5 | -3 | -2 |
| 180 |  |  | -30 |

Intermediate FrequencyFilter

| Frequency <br> （kHz） | Gain（dB） |  |  |
| :---: | :---: | :---: | :---: |
|  | Min． | Typ． | Max． |
| 2.4 |  |  | -35 |
| 4.3 | -4 | -3 | -1 |
| Ref 5.4 |  | 0 |  |
| 6.5 | -5 | -3 | -2 |
| 11.6 |  |  | -35 |

## APPLICATION SCHEMATIC INFORMATIONS



Notes：1．These capacitors might not be necessary if the overall power supplies decoupling is sufficient．
2．The value of these capacitors depends on the crystal parameters．

## APPLICATION SCHEMATIC DIAGRAM



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## PACKAGE MECHANICAL DATA

28 PINS－PLASTIC CHIP CARRIER


| Dimensions | Millimeters |  |  |  | Inches |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | Min． | Typ． | Max． | Min． | Typ． | Max． |
| A | 12.32 |  | 12.57 | 0.485 |  | 0.495 |
| B | 11.43 |  | 11.58 | 0.450 |  | 0.456 |
| D | 4.2 |  | 4.57 | 0.165 |  | 0.180 |
| D1 | 2.29 |  | 3.04 | 0.090 |  | 0.120 |
| D2 | 0.51 |  |  | 0.020 |  | 0.430 |
| E | 9.91 |  | 10.92 | 0.390 |  |  |
| e |  | 1.27 |  |  | 0.050 | 0.300 |
| e3 |  | 0.62 |  |  | 0.018 |  |
| F |  | 0.71 |  |  | 0.028 |  |
| F1 |  |  |  |  | 0.049 |  |
| G |  | 1.24 |  |  | 0.045 |  |
| M1 |  |  |  |  | 0.04 |  |

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